Chapter 1

Introduction to CMOS Design

This chapter provides a brief introduction to the CMOS (complementary metal oxide semiconductor) integrated circuit (IC) design process (the design of "chips"). CMOS is used in most very large scale integrated (VLSI) or ultra-large scale integrated (ULSI) circuit chips. The term "VLSI" is generally associated with chips containing thousands or millions of metal oxide semiconductor field effect transistors (MOSFETs). The term "ULSI" is generally associated with chips or more, MOSFETs. We'll avoid the use of these descriptive terms in this book and focus simply on "digital and analog CMOS circuit design."

We'll also discuss setting up the LASI (layout system for individuals) layout software for Windows and provide a very brief introduction to SPICE (simulation program with integrated circuit emphasis).

1.1 The CMOS IC Design Process

The CMOS circuit design process consists of defining circuit inputs and outputs, hand calculations, circuit simulations, circuit layout, simulations including parasitics, reevaluation of circuit inputs and outputs, fabrication, and testing. A flowchart of this process is shown in Fig. 1.1. The circuit specifications are rarely set in concrete; that is, they can change as the project matures. This can be the result of trade-offs made between cost and performance, changes in the marketability of the chip, or simply changes in the customer's needs. In almost all cases, major changes after the chip has gone into production are not possible.

This text concentrates on custom IC design. Other (noncustom) methods of designing chips, including field-programmable-gate-arrays (FPGAs) and standard cell libraries, are used when low volume and quick design turnaround are important. Most chips that are mass produced, including microprocessors and memory, are examples of chips that are custom designed.

The task of laying out the IC is often given to a layout designer. However, it is extremely important that the engineer can lay out a chip (and can provide direction to the layout designer on how to layout a chip) and understand the parasitics involved in the layout. Parasitics are the stray capacitances, inductances, pn junctions, and bipolar transistors, with the associated problems (breakdown, stored charge, latch-up, etc.). A fundamental understanding of these problems is important in precision/high-speed design.



Figure 1.1 Flowchart for the CMOS IC design process.

1.1.1 Fabrication

CMOS integrated circuits are fabricated on thin circular slices of silicon called wafers. Each wafer contains several (perhaps hundreds or even thousands) of individual **chips or** "**die**" (Fig. 1.2). For production purposes, each die on a wafer is usually identical, as seen in the photograph in Fig. 1.2. In Fig. 1.2, an individual die has been outlined with a black marker and appears next to a dime. Added to the wafer are test structures and process monitor plugs (sections of the wafer used to monitor process parameters).



Figure 1.2 CMOS integrated circuits are fabricated on and in a silicon wafer.

The ICs we design and lay out using a layout program can be fabricated through MOSIS (http://mosis.org) on what is called a **multiproject wafer**; that is, a wafer that is comprised of chip designs of varying sizes from different sources (educational, private, government, etc.). MOSIS combines multiple chips on a wafer to split the fab cost among several designs to keep the cost low. MOSIS subcontracts the fabrication of the chip designs (multiproject wafer) out to one of many commercial manufacturers (vendors). MOSIS takes the wafers it receives from the vendors, after fabrication, and cuts them up to isolate the individual chip designs. The chips are then packaged and sent to the originator. A sample package (40-pin ceramic) from a MOSIS-submitted student design is seen in Fig. 1.3. Normally a cover (not shown) keeps the chip from being exposed to light or accidental damage.



Figure 1.3 How a chip is packaged (a) and (b) a closer view.

Note, in Fig. 1.3, that the chip's electrical signals are transmitted to the pins of the package through wires. These wires (called "bond wires") electrically bond the chip to the package so that a pin of the chip is electrically connected (shorted) to a piece of metal on the chip (called a bonding pad). The chip is held in the cavity of the package with an epoxy resin ("glue") as seen in Fig. 1.3b.

The ceramic package used in Fig. 1.3 isn't used for most mass-produced chips. Most chips that are mass produced use plastic packages. Exceptions to this statement are chips that dissipate a lot of heat or chips that are placed directly on a printed circuit board (where they are simply "packaged" using a glob of resin). Plastic packaged (encapsulated) chips place the die on a lead frame (Fig. 1.4) and then encapsulate the die and lead frame in plastic. The plastic is melted around the chip. After the chip is encapsulated, its leads are bent to the correct position. This is followed by printing information on the chip (the manufacturer, the chip type, and the lot number) and finally placing the chip in a tube or reel for shipping to a company that makes products that use the chips. Example products might include chips that are used in cell phones, computers, microwave ovens, printers.

Layout and Cross Sectional Views

The view that we see when laying out a chip is the top, or layout, view of the die. However, to understand the parasitics and how the circuits are connected together, it's important to understand the chip's cross-sectional view. Since we will often show a layout view followed by a cross-sectional view, let's make sure we understand the difference and how to draw a cross-section from a layout. Figure 1.5a shows the layout (top) view of a pie. In (b) we show the cross-section of the pie (without the pie tin) at the line indicated in (a). To "lay-out" a pie we might have layers called: crust, filling, caramel, whipped-cream, nuts, etc. We draw these layers to indicate how to assemble the pie (e.g., where to place nuts on the top). Note that *the order we draw the layers doesn't matter*. We could draw the nuts (on the top of the pie) first and then the crust. When we fabricate the pie, the order does matter (the crust is baked before the nuts are added).



Figure 1.4 Plastic packages are used (generally) when the chip is mass produced.



(b) Cross-sectional view

Figure 1.5 Layout and cross sectional view of a pie (minus pie tin).

1.2 Using the LASI Program

The LASI program discussed in this section can be used for the layout and design of CMOS integrated circuits. This section provides a brief tutorial covering the use of LASI. We assume that the reader has downloaded and installed LASI and the MOSIS setups following the instructions at cmosedu.com. We use the MOSIS setups (with a design directory of, for example, C:\Lasi7\Mosis) for our examples in this section.

1.2.1 The Basics of LASI

A chip design should reside in a design directory. The LASI system executables are located in C:\Lasi7 (which *cannot* be used as a design directory). Information on setting up a design directory can be found at cmosedu.com.

Starting LASI

Going to the Window's start button, then Lasi 7, and then MOSIS results in LASI starting, Fig. 1.6. Notice how, at the top of the window in Fig. 1.6, the design directory (Folder) is shown. The menu items (**Help, Run, Print**, etc.) are executable by either clicking on the word (e.g., **Help**) or on the menu button (e.g., the picture of a question mark). The buttons on the right of the display can be toggled by either pressing the **Menu1** or **Menu2** buttons or by clicking the right mouse button while in the drawing area. We'll talk about the items on the bottom of the screen in a moment.

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Figure 1.6 Starting LASI using the MOSIS setups.

Getting Help

The LASI layout system comes with a complete on-line manual. This manual is accessible, while LASI is running, by pressing F1 on the keyboard and clicking the command button (simultaneously) with which the user needs help or by pressing the **Help** button. Alternatively, the user can open the help file in the directory C:\Lasi7\help without LASI running.

Cells in LASI I

Complex IC designs are made from simpler objects called cells. A cell might be a logic gate or an op-amp. When LASI starts-up, as seen in Fig. 1.6, the last cell loaded (prior to exiting LASI) appears in the load cell window. In Fig. 1.6, this cell's name is "ALLMOSIS." Let's create a new cell called "test" with a rank of 1. Figure 1.7 shows the resulting LASI screen. Notice that the current cell's name and rank are displayed at the top of the window. If we want to load or create a different cell, we press either the Load menu item or the corresponding picture, as indicated in Fig. 1.7. The drawing area in Fig. 1.7 shows a reference indicator (the origin of the drawing). To toggle displaying this indicator, we can either press **r** on the keyboard or the **R** button in the lower right corner of the display followed by redrawing the cell. To redraw the cell, we press **Enter** on the keyboard or **Draw** or the picture of the pencil at the top of the window.



Figure 1.7 Screen after making a cell called "test" with a rank of 1.

Navigating

Pressing the **Grid** button on the right of the screen followed by zooming in around the reference indictor by pressing **Zoom** (and two clicks of the mouse to indicate the zoom area) on the top menu may result in a screen like the one seen in Fig. 1.8. The reader should experiment with the **Fit** (alt+f), **Xpnd** (alt+x or expand), and the arrow (**Left**, **Up**, **Dn**, and **Right**) commands. The center command, **Cntr**, centers the screen around a point set by the mouse. Pressing **Last** on the top menu brings up the previous (or last) view.

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Figure 1.8 Navigating in LASI (see text).

Drawing a Box

Let's draw a box. To start, select the **Layr** command and select "NWEL" or layer 42. This is the n-well layer discussed in the next chapter. Remember that if a command isn't showing, toggle the menus by right clicking the mouse in the drawing area or pressing the buttons **Menu 1** or **Menu 2**. Next select the **Obj** (object) command followed by selecting BOX (double click on the word BOX). The lower left of the display should indicate a working grid (Wgrd) of 1, a dot grid (Dgrd) of 1, a box object, and the n-well layer. Next click on the **Add** button (we want to add a box on the n-well layer). The lower left of the display should indicate that LASI is in the "Add Box" mode. By clicking the left mouse once in the drawing area, moving the mouse, and clicking the left mouse button again, we draw a box on the n-well layer. Figure 1.9 shows a possible resulting display.



Figure 1.9 Drawing a box using LASI.

Moving and Resizing

Moving or resizing an object consists of *getting* the object using, among others, the **Get** command, *moving* the object using the **Mov** command, and *putting* (or deselecting) the object using the **Put** command. For example, say we want to move the right edge of the n-well box in Fig. 1.9. To begin, select the **Get** command. This is followed by clicking the left button of the mouse on one side of the edge followed by clicking (the mouse) on the other side of the edge (the selected or "Got" edge then becomes highlighted). Using the **Mov** command, we can then use the mouse in the same manner to move the edge. To deselect the edge, we use the **Put** command (again, in the same manner with the two clicks of the left mouse button) or we simply press the all put (**Aput**) command. Note that movement is relative to the clicking of the mouse (we don't have to click on the selected edge). If, for example, the mouse is left-clicked again, the selected edge will move horizontall distance of 5. (The user should experiment with these commands until they feel comfortable.) To move the entire box, we get all four sides of the box or any part of the box using the **Fget** (full get) command.

To reduce the amount of mouse clicking it is helpful to use the **Qmov** (quick move) command. This command automatically performs the get, move, and put commands in sequence so the user doesn't have to keep clicking menu items. The reader should try out the **Qmov** command in LASI. **Qmov** can save considerable time when making edits to layouts.

The Drawing Grids

The position of the cursor in the drawing window is continuously read out at the bottom of the screen. The value of the working grid (what the cursor snaps to) and the dot grid (the dots we see when the **Grid** button is depressed) are also seen at the bottom of the window. The coordinates of the cursor are either in *working grid* units or in the smallest possible grid unit, the *unit grid* (so that the cursor appears to move smoothly instead of jumping around). For the MOSIS setups, there are 100 grid units between each working grid point when the working grid is 1. By pressing the **Wgrd** and **Dgrd** buttons, the respective working or dot grids are changed between one of ten possible values. These values are set using the **Cnfg** command. (Again, if a command isn't showing, toggle the menus by right clicking in the drawing window.) Figure 1.10 shows the **Cnfg** (configure drawing parameters) window. In the MOSIS setups, we've limited the grids to either 1 or 0.5. Until the user gets familiar with layout, it's not a good idea to change these values. Note that it's possible to have a dot grid of 1 while the working grid (the grid the cursor snaps to) is 0.5.



Figure 1.10 Showing how the working and dot grids are set in LASI using the **Cnfg** command.

Keyboard button \mathbf{a} is a toggle between the working and unit grids. Pressing keyboard button \mathbf{w} causes the cursor to snap to the working grid while pressing \mathbf{u} causes the cursor to snap to the unit grid (i.e., appear to move in a continuous movement).

Making Measurements

LASI makes measurements using the keyboard buttons, z and **spacebar**. Pressing the z button sets a zero reference point. Pressing the **spacebar** displays the distance between the cursor and the zero reference point in the middle bottom of the window. It's useful to remember at this point is that pressing **w** forces the cursor to snap to the working grid so that measurements can be made based on the grid and independent of the state (the current selected command) of LASI. Note that if the **spacebar** is held down, a continuous measurement is displayed on the bottom of the window.

Key Assignments

Below is a summary of the keyboard (button) commands.

Enter does a Draw command (redraws the display) Delete does a Del command (deletes the selected objects) Insert does a Xpnd command (expands the current view) Home does a Cntr 0 0 command (centers the display on the origin [reference marker]) End does a Last command (switches back to the previous displayed view) pgup pans up by a full screen pgdn pans down by a full screen arrows pan the drawing window in the direction of the pressed arrow Tab toggles the mouse cursor between a small cross and crosshairs z sets a measurement zero point spacebar gives a measurement from the zero point

The following keyboard buttons are also executed by pressing on the button in the lower right portion of the display

w forces the cursor to the working grid
u forces the cursor to the unit grid
c toggles the path center line on and off in a path object
d toggles the distance marker on and off
i toggles the cell image on and off
o toggles the outline name on and off
o toggles the octagonal cursor mode on and off
r toggles the 0,0 reference mark on and off
t toggles the text reference point on and off
v toggles viewing vertices of a path or polygon object

The alt button can be used with the indicated letter in the top menu commands for execution directly from the keyboard. For example, using alt+u (pressing alt followed by u or pressing both at the same time) results in executing an Undo command. Other multipurpose buttons include the Ctrl, Esc, and Shift buttons (see the LASI help manual for additional information).

Finally note that pressing **Esc** (the escape key) aborts a command including a **Draw** command. Using this command can be useful when the layout gets complicated and large. Pressing escape stops the redrawing and shows the cells as simple outlines.

Cells in LASI II

Let's take the *test* cell in Fig. 1.9 and add it to a cell called *test2*. To begin, we press the **Load** command button and create a cell called *test2*. LASI will ask if we want to save the current cell, *test*, (select yes). Next LASI will ask what rank we want to assign the *test2* cell. Select a rank of 2. A new cell will be created and the drawing window will become blank.

The rank is used in the cell collection's (seen by pressing List) hierarchy. We might rank a *MOSFET* cell with 1, an *inverter* cell with 2, and a *counter* cell with 5. The *MOSFET* cell can be placed in the *inverter* or the *counter* but the *inverter* or *counter* can't be placed in the *MOSFET*. Similarly, we can place the *inverter* (2) in the *counter* (5) but we can't place the *counter* in the *inverter*. Note that to organize the cell collection we go to the system menu (by pressing System) and then press Organize.

We can add a box, as we did before, or we can add rank 1 cells to the rank 2 cell. Let's add our *test* cell seen in Fig. 1.9 to this *test2* cell. Press the **Add** command button. Next select the **Obj** command button and double click on the cell *test*. Moving the mouse cursor into the drawing display shows something similar to what's seen in Fig. 1.11. Notice the small outline of the *test* cell. Before adding the cell (by clicking the left mouse button in the drawing window), let's use the zoom command to zoom in around the reference indicator. Adding several *test* cells to the *test2* cell may look something like what is seen in Fig. 1.12.

We can go back to the *test* cell by pressing **List** (saving the *test2* cell) and double clicking on the cell *test*. Press **alt+f** (or **Fit**) at the top of the menu to fit the cell's contents to the drawing window. Let's add another box on the n-well layer (select **Add**, then **Obj**, double clicking on BOX, and then **Layr** followed by selecting the layer NWEL). Adding another n-well box to our layout may result in a layout similar to what appears in Fig. 1.13.

Going back to the *test2* cell, Fig. 1.14, we see that the changes in the layout are automatically updated in the higher ranking cell. If, for example, a change was made to the layout of an inverter, then going to the lower ranking inverter cell and making the change (once) will automatically update the layout wherever the inverter cell is used.

Notice, in Fig. 1.14, that there is a dotted line surrounding the shape of the *test* cell. These dotted lines are the image of the cell. In addition, there are small diamonds in each of the added *test* cells. These diamonds indicate where the reference indicator is in



Figure 1.11 Adding the test cell with a rank of 1 to the test2 cell with a rank of 2.



Figure 1.12 Adding several "test" cells with a rank of 1 to the "test2" cell with a rank of 2.

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Figure 1.13 Going back to the "test" cell and adding a additional n-well box.



Figure 1.14 How the change to the "test" cell propagates up through the hierarchy.

the *test cell*. Moving or redefining the location of the reference indicator in the lower ranking cell, using the **Orig** command, also shifts the cells' locations in the higher-ranking cells where it is used. Pressing i on the keyboard or the I button at the bottom of the display toggles the cell's image on and off. (To see the change, the drawing window must be redrawn by pressing on the keyboard or using the **Draw** command.)

Moving a Cell

To move a cell, the **Cget** (cell get) command is used first. Double clicking on the cell or using the mouse to surround a cell (or cells) "gets" the cell. This is followed by using the **Mov** command. Deselecting the cells can be accomplished using the **Cput** (cell put) command or, more often, using the **Aput** (all put) command.

Viewing or Editing Specific Layers

When layouts get complicated, the ability to look at or edit specific layers becomes important. However, someone learning layout can also feel frustrated by not knowing how the viewing and editing of specific layer commands operate. Below we summarize these commands.

Ldrw Draws only one layer of the layout. Useful to quickly view a single layer.

View Selects the layers LASI displays in the drawing window. This command can be frustrating. For example, suppose the NWEL layer is deselected in the view menu. If we were to draw a box on the NWEL layer and then redraw the layout, the box we just drew wouldn't show up!

Open Selects the layers LASI will allow the user to "get." This command, again, can result in frustration. If, for example, the NWEL layer is not selected in the open menu, then trying to "get" the layer will result in a waste of time.

The Polygon and Path Shapes

The only drawing shape we've discussed so far is the box. LASI can also be used to make polygons and path shapes. Let's start out by drawing a polygon (say a triangle). Create a new cell (using the Load command) called test3 with a rank of 1. Select Add, then Obj (double clicking on PATH/POLY). Let's also select a different layer using the Layr command (select POL1 or layer 46). Next click the Wdth command and make sure that width is set to 0. When the width is zero, the object is a polygon. When the width is nonzero, the object is a path. Figure 1.15 shows the layout of a polygon (not closed). Notice the location of the polygon's vertices. To move (or change) the shape of a polygon, we must get a vertex. Using the Get command on a side of a polygon, and not encompassing a vertex, can result in frustration. To show the polygon's (or path's) vertices in the drawing display, press v on the keyboard (or the V in the lower right corner of the display) followed by Enter. (Try this now.) To close the polygon object in Fig. 1.15, we place the last (fourth) vertex on the first vertex as seen in Fig. 1.16. Note that this last vertex is still active and so it appears that we are still drawing the same polygon (even though our triangle is closed). To draw another shape, click the Aput command.



Figure 1.15 Drawing a polygon in LASI on the POL1 (polysilicon) layer.



Figure 1.16 Closing the polygon in Fig. 1.15 and drawing a path object with a width of 4.

Also seen in Fig. 1.16 is a path object. To draw a path, after drawing the polygon shape, all we have to do is use the **Wdth** command to set the width of the path to a nonzero number (zero width indicates that we're drawing a polygon). For the path in Fig. 1.16, we used a width of 4. To terminate drawing a path, we can use the **Aput** command. Notice how the vertices of a path are located in the center of the path. Again, to toggle between displaying or not displaying vertices, we can press v on the keyboard. Also, again, if we don't encompass a vertex when we are trying to get the object, nothing will get selected. (Trying to get the side of a path or polygon can result in frustration.) To move an entire path or polygon, we can use the **Fget** command and encompass at least one of the path's or polygon's vertices.

Using Text in LASI

Labeling layout with text is important for documenting how the IC is assembled. To add text to a layout, we select the **Text** command. This is followed by selecting the text's layer using the **Tlyr** command (select POL1 for the example to follow). Next the size of the text can be set using **Tsiz**. The command **Font** (remembering if the command isn't showing to right-click the mouse in the drawing display) selects one of three font files. The first font (C:\LASI7\TFF1.DBD) file uses zero-width letters (so they don't have any fabrication significance). The other files (TFF2.DBD and TFF3.DBD) do have widths, and so they can be seen in the fabricated chips. Clicking the left mouse button in the drawing display may result in the text seen in Fig. 1.17 (where we've changed the size



Figure 1.17 Adding text to a layout.

using **Tsiz**). To move the text, we must encompass a text vertex. To show the text vertices, press **t** on the keyboard or **T** in the lower right corner of the display followed by a **Draw** command. Again, not knowing to get a vertex can lead to frustration. To get text in a layout without getting any of the other objects, we can use the **Tget** command. To change the size of the text, we "get" the text by encompassing a vertex using the **Get**, **Fget**, or **Tget** commands, and then using the **Csiz** command. Using the **Text** command and clicking on an existing text vertex results in changing the displayed text but not the size or layer of the existing text. The **Clyr** command can be used to change the layer the text is drawn on or any other shape's layer.

Some Features to Speed Up Layout Design

The reader's right hand should be used for the mouse (assuming the reader is right-handed) while the left hand should be used for pressing keys on the keyboard. To assign more commands to the keyboard, press the **Cnfg** button followed by the **Fkeys** button. Figure 1.18 shows the result. The **F1** key is used for getting help, as discussed earlier. Now, as seen in Fig. 1.18, pressing **F2**, **F3**, and **F4** executes the commands **Aput**, **Qmov**, and **Fget**, respectively. It's important, when adding commands, to ensure that the changes are saved prior to exiting the window. To add a command to the list, click on one of the existing commands. Next type the new command in the command argument field at the bottom of the window. Pressing **Add** places the new command after the selected existing command, while pressing **Insert** places the command before the existing command. To edit an existing command, double click on it. After editing, press **Paste** to update the existing command. Again, it's important to **Save** the changes prior to exiting.

| Fkeys | Single Click to Select | Double Click to Edit |
|--------------|------------------------|----------------------|
| aput DMOV | | |
| FUEI | | |
| | | |
| | | |
| | | |
| | | |
| | | |
| | | |
| | | |
| Command Argu | ments | |
| Command Argu | ments | |

Figure 1.18 Setting up the Fkeys to speed up layout.

Some other useful commands that can speed up layout, when the layout contains a large number of cells, are the **Outl**, **Full**, and **Dpth** commands. To avoid having to redraw the contents of a cell or cells, the **Outl** (outline) command can be used. Either double-clicking on a cell or surrounding the cell's contents with the mouse, when the **Outl** command is selected, causes the cells to be drawn as outlines. Pressing **n** on the keyboard or **N** with the mouse cursor in the lower right portion of the display, toggles the cell's name in its outline on and off. Using the **Full** command shows the contents of the cell.

If we are editing a cell with lower ranking cells nested in it, then we can use the **Dpth** (depth) command to limit the full display of these lower ranking cells. If depth is set to 0, then only the basic objects (boxes, paths, text) in the current-edited cell are shown in detail. The lower level cells are shown as dashed outlines. If the depth is set to 1, then the basic objects in the next level of nested cells are shown ... and so on. Note that cell nesting levels are not the same as cell rank. To show the basic objects of all possible nested cells, the depth should set to 15. To see a listing of nested cells within other cells, use the **Show** command.

Finally, when editing both cells and objects (boxes, polygons, and paths) the window get, **Wget** (window get) and, **Wmov** (window move) commands can be very useful. While in the **Wget** command mode, the mouse is used to select an area of layout containing both cells and drawn objects. The **Wmov** command moves this layout. Note that when "getting" the layout a cell won't be selected unless it is completely surrounded in the mouse selection area.

Understanding the Cpy and Copy Commands

The **Cpy** command is used to copy layout within a cell. The layout is selected using, for example, the **Fget**, **Cget**, or **Wget** commands. The **Cpy** command then behaves just like a move command except that the selected layout isn't moved to the new location: it is copied.

It's important to understand that using the **Cpy** command frequently is not a good idea. For example, say a memory cell containing 50 objects (boxes, polygons, or paths) is laid out. If the memory cell is used in a 1 Mbit memory, and the **Cpy** command is used, then the resulting number of objects in the memory cell is 50 million (this is bad). If, on the other hand, the 1 Mbit memory is made with the 1,000,000 memory cells, then the size (the number of objects) is 1,000,050. We can take this a step further. We can make a cell containing a row of memory cells (say 1,000) and use this row cell 1,000 times to make a 1 Mbit memory. The number of objects in the 1 Mbit memory cell is now only 2,050 (1,000 instances of the memory row, 1,000 instances of the layout file. **Using cell hierarchy is extremely important.** Do not lay out a large chip unless the material in this paragraph is understood! Else the design file sent to the mask maker will be unreasonably large. Use the **Cpy** command as little as possible.

Using the **Save** command saves the contents of the cell we are working on. It can also be used to save the cell under a different name. However, sometimes we want to take some portion of the layout we are working on and move it (append it) to a different cell (or a new cell). The **Copy** command is useful for this task. To take some layout and append it to a different cell, we first "get" the layout we want to copy to a different cell. Next we select the **Copy** command and the cell we want to move the selected layout into (or the name of a new cell).

Transporting Cells in LASI

To share files between other users or between design directories, *Transportable LASI Cell* files (*.TLC) files or *Transportable LASI Drawing* files (*.TLD) files are used. The files we draw in LASI are saved on the hardisk as text files with the TLC extension.

Copying TLC files into a directory will **not** make them show up in the design directory's cell listing (and so we won't be able to edit the cells). To register a cell in a design directory, we must first **Import** the cell. Note, in the **System** menu, the **Organize** command can be used to organize the cells in a design directory according to rank or name.

The TLC files contain references to other cells but not the actual layouts of the referenced cells themselves. (For example, a reference may indicate "place the inverter cell at the location 12,13.") To get a file that contains the cell's hierarchy, we use TLD files. To generate a TLD file, we go to the **Export** command and select the name of the cell, TLD file, and the location we want to place the TLD file. TLD files can be shared between users or used as backups of work. Note that while LASI imports a TLD file, it still uses TLC files for editing. Every time **Save** is pressed, the TLC file in the design directory (being edited) is updated, leaving the TLD file unchanged (until the **Export** command is used).

Edit-in-Place

Consider the layout seen in Fig. 1.19. In this layout we have two boxes and two cells. Let's say we want to align the cell on the right to the two boxes. The simplest way to do this (keeping in mind that modifying the cell propagates through the hierarchy) is to get the cell using the **Cget** command. Then press **Ctrl** on the keyboard while pressing **Load**. This causes LASI to enter the "Edit-in-Place" (EIP) mode. A lower ranking cell can then be modified while showing the objects from the higher ranking cell. To exit EIP, use the



Figure 1.19 Editing a cell in place.

Load or **List** commands. Note that the other cells in the layout will not be shown when in EIP mode (only the cell we are editing and the drawn objects from the higher ranking cell).

Backing Up Your Work

It's very important to constantly back up your work in a location other than the hard disk you are running LASI out of. Backups can be as simple as exporting TLD files to a DVD or as complete as copying the design directory (or zipping it up) to a network drive. The point is layout that is laborious so not backing up the work is a mistake.

1.2.2 Common Problems

After adding an object, the object cannot be seen

Check the **View** layers in the drawing display to ensure that the layer is not in hidden mode. The **Draw** command must be used after using **View**.

Cannot Get an object

(1) Check, using the **Open** command, that the layer can be opened (or moved). (2) Verify that the object is not part of another cell. (3) When trying to get an object made using the path or polygon object make sure that the cursor encompasses a vertex. (4) If the object is text, then text vertex must be encompassed.

Cells are drawn as outlines, or the perimeter of a cell has a dashed line

(1) Use the **Full** command to show the contents of a cell. (2) Use the **Dpth** command to limit the depth of the cells shown. Increasing the depth to the rank of the cell shows all cells. (3) Press **i** on the keyboard to force an outline to be drawn around a cell. This is indicated by the **I** in the bottom right corner of the drawing display. The letter **n** (or **N** in the lower right of the display) toggles the display of the cell's name.

Fit command causes the drawing window to expand much larger than the current cell

There is an unknown object someplace in the cell. Use the **Fget** command to get any objects outside the main cell area. Use the **Del** command to delete the unknown object.

Cursor movement is not smooth

(1) The cursor may be in the octagonal mode. Press $\mathbf{0}$ on the keyboard or the button \mathbf{O} in the lower right portion of the display to toggle this mode on and off. (2) Make sure that the display isn't zoomed in too much. (3) Pressing \mathbf{a} can be used to toggle the mouse cursor between the working and unit grids.

1.2.3 Sending the Layout to the Mask Maker

Once we have a completed layout we can convert the resulting TLC files into a format the mask maker will accept. These formats are either CIF (CalTech intermediate format) or GDS (graphical design system, which is a derivative of the older Calma stream format, CSF). We'll focus on using GDS (at the time of this writing the format is actually a second-generation standard called GDSII) since it is what is used in industry. Generating a *.GDS file in LASI (or any other layout program) is often called *streaming the layout out*. Because GDS files can be large, and they are often stored on magnetic storage tapes, generating and storing the GDS file is often called "taping out" or simply "tape-out."

Assuming the layout is saved, we enter the **System** mode in LASI, Fig. 1.20. Next, we select the **Tlc2Gds** command button, Fig. 1.21. The specific details concerning using this utility or the **Gds2Tlc** utility can be found in the on-line manual. One of the important parameters in the setups is the scale factor Lambda. This takes our layout drawn on a "1" grid and scales it to the appropriate final size.

Checking to Make Sure the Layout Scaled Correctly

To ensure that the layout scales correctly when making the GDS file, copy the design directory into a temporary design directory (TDD). LASI is then set up to run from this TDD. This ensures that all of the original layout isn't corrupted by mistakes in the checking process we're about to discuss (**important**). It's also a good idea to back up the directory at this point as well.

In this TDD we can generate a GDS file, using the **Tlc2Gds** utility. Unless, the user has some atypical needs (e.g., eliminating layers in the final GDS file), this is a simple matter of specifying the name of the TLC file to convert (ensuring the TLC file in the dummy directory is used), specifying the name of the GDS file to create from the TLC file, specifying the scale factor, and starting the conversion (pressing **Go**) after exiting the setups. Both GDS and layer data map (*.ldm) files are generated. (The user will have to select the layers to add to the ldm file while the conversion is in progress unless an ldm file already exists.) The *.ldm file is used when converting the GDS back into a TLC file discussed below.

| vstem Mode | Э | Orga | nize before | running a L | Itility | | |
|------------|---------|---------|-------------|-------------|----------|---------|---------|
| Gds2Tlc | Cif2Tlc | Dxf2Tlc | LasiDrc | LasiFlat | LasiLL | Lasi3D | Clone |
| Tlc2Gds | Tlc2Cif | Tlc2Dxf | LasiCkt | LasiMx | LasiCode | MakeTff | Scale |
| Message: | 8 | | | | | | Show |
| | | | | | | | Remove |
| | | | | | | | ReName |
| | | | | | | | ReSize |
| | | | | | | | ReRank |
| | | | | | | | Bel ave |
| | | | | | | | |

Figure 1.20 The LASI System Screen.

| 🗄 LASE7 Cell: TFST Rank: 1 Folder: C:\Lasi7\Mosis | | 1000 |
|--|----------|------|
| He 💑 TIC2Gds 7 o Redo Save Load Recall List Left Up Dn Right Fit Cntr Xpnd Zoom La | ast Drav | N |
| | Mer | nu 1 |
| | Ldrw | Sdrw |
| | Attr | Show |
| Conversion Satur | Info | Arc |
| Conversion Setup | Sort | Font |
| Main Cell File Name C:\Lasi7\Mosis\Mychip.tlc Browse | Ccel | Csiz |
| CDC File Name Muchin ads | Clyr | Cwth |
| | Layr | Wdth |
| | Swin | Rwin |
| Layer Filter (1-256) 1-7 25-26 26-57 41-46 45-52 56 56-62 | Cmd | Grid |
| Layer Datatype Map File C:\Last7\Mosis\Allmosis.ldm Browse | Wgrd | Dgrd |
| · · · · · · · · · · · · · · · · · · · | View | Open |
| GDS Library Name DEFAULT.DB Lambda in um 0.3 | Obj | Text |
| GDS Units per Phys Unit 1000 Default Path Width 2.e-003 | Add | Del |
| Er Charle for Brane CDS IC Brahan | Get | Put |
| Sout Cells in Ascending Bank Order | Fget | Fput |
| | Cget | Cput |
| | Tget | Tput |
| Lowercase Cell Names Scale Unit LSB Lorrection | Aput | Wmov |
| | Qmov | Cmov |
| Report File Name TIc2gds.rpt OK Cancel | Mov | Сру |
| · · · · · · · · · · · · · · · · · · · | Vstp | Prev |
| ······ | Pbeg | Pend |
| | Cut | Join |
| Wgrd=1 Dgrd=1 Obi=PATH Layr=MET6 Wdth=4 Using Layer Table | | |

Figure 1.21 Generating a GDS file from a TLC file.

Scale factor

After the GDS file is generated, we can use the **Gds2Tlc** program to convert the GDS file back into TLC files. In the setups we must specify a directory where the TLC files will be written, for example, C:\temp. We can't use a drawing directory because then the existing TLC files would be overwritten. After we've converted the GDS back into TLC files, we can **Import** the (scaled) TLC files into the dummy directory to make sure the generated GDS file is scaled correctly.

Note, for the sake of feeling comfortable with this process, that it's easy to take a simple cell, like the *test* cell in Fig. 1.9 and convert it back and forth between a GDS file and a TLC file (with scale factor). Also note that we can use the **Resize** command on the system menu to change the size of the layout if needed.

1.3 An Introduction to WinSPICE

The simulation program with an integrated circuit emphasis (SPICE) is a ubiquitous software tool for the simulation of circuits. In this book we'll use WinSPICE. See the links at cmosedu.com for download and installation information. WinSPICE, like all SPICE engines, uses a text file netlist for simulation input.

Generating a Netlist File

We can use, among others, the Window's notepad or wordpad programs. WinSPICE likes to see files with a "*.cir" extension. To save a file with this extension, place the file name and extension in quotes as seen in Fig. 1.22. If quotes are not used, then Windows will tack on ".txt" to the filename. This can make finding the file difficult when we open the netlist with WinSPICE (see Fig. 1.23).



Figure 1.22 Saving a text file with a ".cir" extension.

WinSpice v1.05.01 - 🗆 × File Edit Settings Help © Copyright 1996-2003 OuseTech Ltd. All Rights Reserved. Print 1.05.01 Exit Opening Dec 10 2003 00:47:53 a circuit Shareware version of WinSpice. For non-commercial use only. Please read the file 'license.txt' for conditions of use. netlist. ***** ****** Type "help" for more information, "quit" to leave. WinSpice 1 -> _ < III

Figure 1.23 Opening a file with WinSPICE.

Transient Analysis

A SPICE transient analysis simulates circuits in the time domain (like an oscilloscope the x-axis is time). Let's simulate the simple circuit seen in Fig. 1.24. A simulation netlist (the text file) may look like:

*** Figure 1.25 CMOS: Circuit Design, Layout, and Simulation ***

.control destroy all run plot vin vout .endc .tran 100p 100n Vin Vin 0 DC 1 R1 Vin Vout 1k R2 Vout 0 2k .end Vin



Figure 1.24 Simulating the operation of a resistive divider.

The simulation results using this netlist are seen in Fig. 1.25. The first line in a netlist is a title line. This line is ignored by SPICE (important). The next five lines are control commands. Notice how the end of the control statement is terminated with an ".endc" not an ".end" like at the end of the netlist. Placing ".end" at the end of the control statement causes SPICE to ignore all of the lines containing the circuit information. The statements in the control block can be run directly from the command line in the WinSPICE command window seen in Fig. 1.23. The *destroy all* command destroys all of the previous simulation results (so we don't display old data). The *run* command runs the simulation. The *plot* command plots the voltages on the nodes Vin and Vout.

Note that the DC voltage source Vin is connected to the node Vin. We could have labeled the Vin node with a number like "1." However, it is nice to have node names that correspond with signals.

The connection of the resistors and how they are specified should be easy to determine. A line starting with an "R" indicates a resistor specification. A line beginning with an "*" indicates a comment. Node 0 (zero) is always reserved for ground.

The form of the transient statement (this is the type of analysis) is

.TRAN TSTEP TSTOP <TSTART> <TMAX> <UIC>

where the terms in <> are optional. The TSTEP term indicates the (suggested) time step to be used in the simulation. The parameter TSTOP indicates the simulation's stop time. The starting time of a simulation is always time equals zero. However, for very large (data) simulations, we can specify a time to start saving data, TSTART (again this term is optional). The TMAX parameter is used to specify the maximum step size. If the plots start to look jagged (like a sinewave that isn't smooth), then TMAX should be reduced.



Figure 1.25 Simulating the circuit in Fig. 1.24.

To illustrate a simulation using a sinewave, examine the schematic in Fig. 1.26. The statement for a sinewave in SPICE is

SIN VO VA FREQ <TD> <THETA>

The parameter VO is the sinusoid's offset (the DC voltage in series with the sinewave). The parameter VA is the peak amplitude of the sinewave. FREQ is the frequency of the sinewave, while TD is the delay before the sinewave starts in the simulation. Finally, THETA is used if the amplitude of the sinusoid has a damped nature. To simulate the circuit in Fig. 1.26, we use a netlist of

*** Figure 1.26 CMOS: Circuit Design, Layout, and Simulation ***



Figure 1.26 Simulating the operation of a resistive divider with a sinewave input.

Some key things to note in this simulation: (1) MEG is used to specify 10^6 . Using "m" or "M" indicates milli or 10^{-3} . The parameter 1MHz indicates 1 milliHertz. (Also, f indicates femto or 10^{-15} . A capacitor value of 1f doesn't indicate one farad but rather 1 femto Farad.) (2) Note how we increased the simulation time to 3 μ s. If we had a simulation time of 100 ns (as in the previous simulation), we wouldn't see much of the sinewave (one-tenth of the sinewave's period). (3) The "SIN" statement is used in a transient simulation analysis. It is **not** used in an AC analysis.

Before leaving this introduction to transient analysis, let's introduce the SPICE pulse statement. This statement has a format given by

PULSE VINIT VFINAL TD TR TF PW PER

VINIT is the pulse's initial voltage, VFINAL is the pulse's final (or pulsed) value, TD is the delay before the pulse starts, TR and TF are the rise and fall times, respectively, of the pulse (noting that when these are set to zero the step size used in the transient simulation is used); PW is the pulse's width; and PER is the period of the pulse. Figure 1.27 provides an example of a simulation that uses the pulse statement. A section of the netlist used to generate the waveforms in this figure is seen below.

.tran 100p 30n

| Vin | Vin | 0 | DC | 0 | pulse 0 1 6n 0 0 3n 10n |
|-----|------|------|----|---|-------------------------|
| R1 | Vin | Vout | 1k | | |
| C1 | Vout | 0 | 1p | | |



Figure 1.27 Simulating the step response of an RC circuit using a pulsed source voltage.

Other Analysis

Besides the transient analysis presented in this section, we frequently use the SPICE DC and AC analyses. The AC analysis has an x-axis of frequency. This type of analysis is the common "small-signal" analysis used in a basic introductory microelectronics course. The DC analysis has a DC voltage source for the x-axis. The value of the DC source is swept while either a current of voltage is plotted on the y-axis. We don't go into these analyses here but provide numerous examples later in the book.

Convergence

A netlist that doesn't simulate isn't converging numerically. *Assuming* the circuit contains no connection errors, there are basically three parameters that can be adjusted to help convergence: ABSTOL, VNTOL, and RELTOL.

ABSTOL is the absolute current tolerance. Its default value is 1 pA. This means that when a simulated circuit gets within 1 pA of its "actual" value, SPICE assumes that the current has converged and moves onto the next time step or AC/DC value. VNTOL is the node voltage tolerance, default value of 1 μ V. RELTOL is the relative tolerance parameter, default value of 0.001 (0.1 percent). RELTOL is used to avoid problems with simulating large and small electrical values in the same circuit. For example, suppose the default value of RELTOL and VNTOL were used in a simulation where the actual node voltage was within 1 mV of 1 V (1V·RELTOL), while the VNTOL parameter signifies an end when the node voltage is within 1 μ V of 1 V. SPICE uses the larger of the two, in this case the RELTOL parameter results, to signify that the node has converged.

Increasing the value of these three parameters helps speed up the simulation and assists with convergence problems at the price of reduced accuracy. To help with convergence, the following statement can be added to a SPICE netlist:

.OPTIONS ABSTOL=1uA VNTOL=1mV RELTOL=0.01

To (hopefully) force convergence, these values can be increased to

.OPTIONS ABSTOL=1mA VNTOL=100mV RELTOL=0.1

Note that in some high-gain circuits with feedback (like the op-amp's designed later in the book) decreasing these values can actually help convergence.

Some Common Mistakes and Helpful Techniques

The following is a list helpful techniques for simulating circuits using SPICE.

- 1. The first line in a SPICE netlist must be a comment line. SPICE ignores the first line in a netlist file.
- 2. One megaohm is specified using 1MEG, not 1M, 1m, or 1 MEG.
- 3. One farad is specified by 1, not 1f or 1F. 1F means one femto-farad or 10^{-15} farads.
- 4. Voltage source names should always be specified with a first letter of V. Current source names should always start with an I.
- 5. Transient simulations display time data; that is, the x-axis is time. A jagged plot such as a sinewave that looks like a triangle wave or is simply not smooth is the result of not specifying a maximum print step size.
- 6. Convergence with a transient simulation can usually be helped by adding a UIC (use initial conditions) to the end of a .tran statement.
- A simulation using MOSFETs must include the scale factor in a .options statement unless the widths and lengths are specified with the actual (final) sizes.
- In general, the body connection of a PMOS device is connected to VDD, and the body connection of an n-channel MOSFET is connected to ground. This is easily checked in the SPICE netlist.
- Convergence in a DC sweep can often be helped by avoiding the power supply boundaries. For example, sweeping a circuit from 0 to 1 V may not converge, but sweeping from 0.05 to 0.95 will.
- 10. In any simulation adding .OPTIONS RSHUNT=1E8 (or some other value of resistor) can be used to help convergence. This statement adds a resistor in parallel with every node in the circuit (see the WinSPICE manual for information concerning the GMIN parameter). Using a value too small affects the simulation results.

ADDITIONAL READING

- D. E. Boyce, LASI User's Manual, available while LASI is running by pressing F1 on the keyboard and the button the user needs help with (at the same time). Alternatively, the user can open the help file in the directory C:\Lasi7\help.
- M. Smith, WinSPICE User's Manual, Available for download (with the WinSPICE simulation program) at http://www.winspice.co.uk/

PROBLEMS

In the following solutions, it can be very helpful to use the **Prt Sc** (print screen) button on the keyboard to copy contents displayed on the computer's display to the clip board. The image of the display can then be pasted into a document. For ease of viewing (the resulting pasted image in the document), it may also be useful reduce the display resolution prior to using the **Prt Sc** button (right click on the desktop, select properties, then settings).

In the following problems, the solutions should include pictures of the LASI layout screen and discussions indicating that you know what you are doing.

- **1.1** Create a cell called *mycell* with a rank of 1 using LASI. In this cell, draw a 10 by 10 box using the POL1 layer. Place the lower left corner of the box at the origin. Show how to measure the diagonal distance of the box.
- **1.2** Explain how the **Qmov** command can be used to edit the box in Problem 1 so that it measures 5 by 8. How would this be accomplished using **Get**, **Mov**, and **Put**?
- **1.3** What functions do the **Swin** and **Rwin** commands perform? Give an example of where these would be useful.
- 1.4 What functions do the **Cget** and **Cput** commands perform? Can any other commands be used in place of **Cget**?
- **1.5** Write the word "test" on the MET1 layer with sizes of 3, 9, and 24 in the cell of Problem 1 (*mycell*). Discuss the possible ways of "getting" the text and "moving " text.
- **1.6** Using a path and a polygon in the cell (*mycell*) of Problem 1, generate two objects with widths of 10 and lengths of 10 directly next to the box from Problem 1. Discuss the differences in editing boxes, polygons, and paths.
- **1.7** Explain, in your own words, the difference between the **Cpy** and **Copy** commands. Give examples to demonstrate the differences.
- 1.8 Demonstrate how the Wget and Wmov commands function.
- **1.9** Using the POL1 layer, draw a triangle that measures nominally 10 on each side (make sure the layout is snapped to the working grid). How many vertices does the triangle have? Using LASI's measurement tools, measure the length of the triangle's sides.
- **1.10** Circles can be drawn using a polygon (path with zero width) and the Arc command. Show how to draw a circle using LASI. Make sure the steps are clear.
- **1.11** What does the **Clone** system command do? Give an example of how to use this command.
- **1.12** Discuss the different ways cells can be drawn as outlines.
- **1.13** What do the keyboard buttons w, u, a, z, and space do in LASI? Give examples to illustrate your understanding of each key's function.
- 1.14 Describe how to add text in LASI and how to set the text size and layer.
- 1.15 Explain, in your own words and with examples, how to edit a cell in place.
- **1.16** Simulate the operation of the circuit in Fig. 1.28. What happens if you use a pulse frequency that's too high? What happens if your simulation time is too short? Give examples to illustrate your understanding.



Figure 1.28 Circuit used in Problem 1.16